TOSHIBA Transistor Silicon PNP Triple Diffused Type

2SA2142

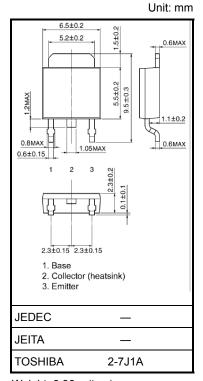
High-Voltage Switching Applications

• High breakdown voltage: V_{CEO} = -600 V

Absolute Maximum Ratings (Ta = 25°C)

Characteristic		Symbol	Rating	Unit	
Collector-base voltage		V_{CBO}	-600	V	
Collector-emitter voltage		V_{CEO}	-600	V	
Emitter-base voltage		V _{EBO}	-7	V	
Collector current	DC	Ic	-0.5	Α	
	Pulse	I _{CP}	-1		
Base current		Ι _Β	-0.25	А	
Collector power dissipation	Ta = 25°C	Pc	1	W	
	Tc = 25°C	FC	15		
Junction temperature		Tj	150	°C	
Storage temperature range		T _{stg}	-55 to 150	°C	

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.



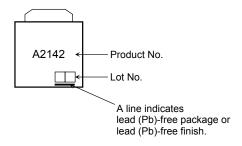
Weight: 0.36 g (typ.)

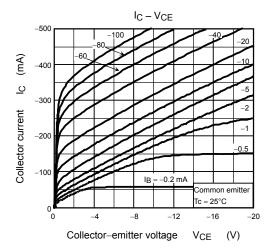
Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

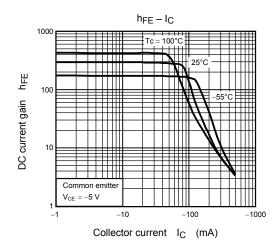
Electrical Characteristics (Ta = 25°C)

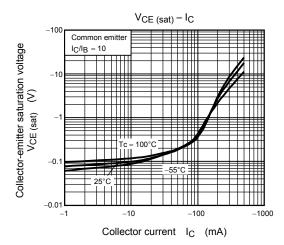
Charac	Characteristic Symbol Test Condition		Min	Тур.	Max	Unit	
Collector cutoff curre	nt	I _{CBO}	$V_{CB} = -600 \text{ V}, I_{E} = 0$		_	-10	μΑ
Emitter cutoff current		I _{EBO}	$V_{EB} = -7 \text{ V}, I_{C} = 0$	_	_	-1	μΑ
Collector-emitter brea	akdown voltage	V (BR) CEO	$I_C = -10 \text{ mA}, I_B = 0$	-600	_	_	V
DC current gain		h _{FE} (1)	$V_{CE} = -5 \text{ V}, I_{C} = -1 \text{ mA}$	70		500	
		h _{FE} (2)	$V_{CE} = -5 \text{ V}, I_{C} = -50 \text{ mA}$	100	_	400	
Collector-emitter satu	ıration voltage	V _{CE (sat)}	$I_C = -100 \text{ mA}, I_B = -10 \text{ mA}$	_		-1.0	V
Base-emitter saturati	on voltage	V _{BE (sat)}	$I_C = -100 \text{ mA}, I_B = -10 \text{ mA}$		-0.76	-0.9	V
Transition frequency		f _T	V _{CE} = -5 V, I _C = -50 mA		35	_	MHz
Collector output capa	icitance	C _{ob}	VCB = −10 V, IE = 0, f = 1 MHz	_	24	_	pF
Switching time	Rise time	t _r	Output $ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	_	0.2	_	
	Storage time	t _{stg}		_	2.3		μs
	Fall time	t _f	I _{B1} = −10 mA, IB2 = 20 mA, Duty Cycle ≤ 1%	_	0.2	_	

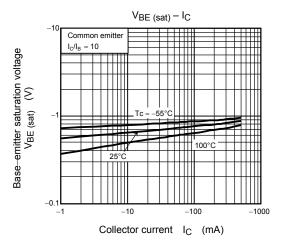
Marking

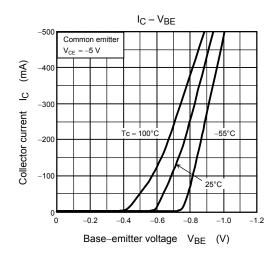




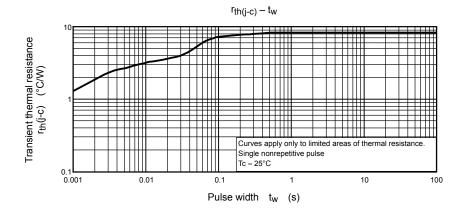


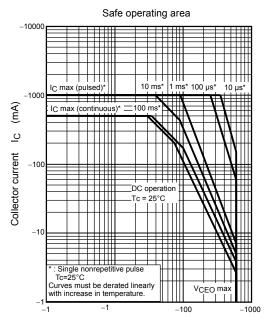






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Collector-emitter voltage V_{CE} (V)

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